MA4P7455-1225



Quad PIN Diode π Attenuator 10 - 4000 MHz

M/A-COM Products Rev. V2

Features

- 4 PIN diodes in a SOT-25 Plastic Package
- Externally Selectable Bias and RF Matching Network
- 10 4,000 MHz Useable Frequency Band
- + 43 dBm IP3 @ 1000 MHz (50 Ω)
- 1.0 dB Loss @ 1000 MHz (50 Ω)
- 30 dB Attenuation @ 1000 MHz (50 Ω)
- Lead-Free SOT-25 Package
- 100% Matte Tin Plating over Copper
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible
- RoHS* Compliant Version of MA4P274-1225

Description

M/A-COM's MA4P7455-1225 is a wideband, lower insertion loss, high IP3, Quad PIN diode π attenuator in a low-cost, lead free surface mount SOT-25 package. Four PIN diodes in one package reduce design parasitics and improve circuit density.

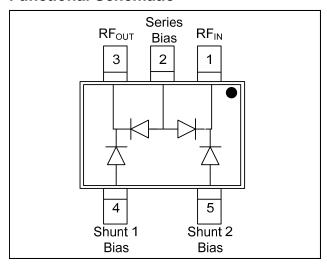
These PIN diode attenuators perform well where RF signal amplitude control is required in 50 Ω handset circuits and 75 Ω broadband CATV systems. Exceptional insertion loss, attenuation range, and IP3 at <10 mA bias make these devices suitable for better power level control in RF amplifiers.

Ordering Information¹

Model No.	Package
MA4P7455-1225T	Tape and Reel
MADP-007455-001SMB	Sample Board

1. Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	RF IN	4	Shunt 1 Bias
2	Series Bias	5	Shunt 2 Bias
3	RF OUT		

Absolute Maximum Ratings^{2,3}

Parameter	Absolute Maximum
Operating Temperature	-65 °C to +125 °C
Storage Temperature No Dissipated Power	-65 °C to +150 °C
DC Voltage at Temperature Extremes	- 100 V
DC Current	75 mA

- 2. Exceeding any one or combination of these limits may cause permanent damage to this device.
- 3. M/A-COM does not recommend sustained operation near these survivability limits.

 ^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macom.com for additional data sheets and product information.

MA4P7455-1225



Quad PIN Diode π Attenuator 10 - 4000 MHz

M/A-COM Products Rev. V2

Typical 50 Ω Performance⁴ @ 25°C using Wideband RF Circuit Design

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	+3 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias 1000 MHz	dB	_	-2.0	_
Insertion Loss	+6.5 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias 1000 MHz	dB	_	-1.0	
Return Loss	+6.5 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias 1000 MHz	dB	_	-10	_
Attenuation	0 mA - Series Diode Bias / 0.75 V - Shunt 1 and 2 Bias 1000 MHz	dB	_	-29	_
Input IP3	0 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias +6.5 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias F1 = 1000 MHz, F2 = 1100 MHz	dBm dBm		43 43	
Input IP3	0 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias +6.5 mA Series Diode Bias / 0.75 V Shunt 1 and 2 Bias F1 = 100 MHz, F2 = 110 MHz	dBm dBm		43 33	
Settling Time	Within 1 dB of Final Attenuation Value 1000 MHz	μS	_	3	_
RF C.W. Incident Power	0 - 20 V Series Diode Bias / 0.75 V Shunt 1 and 2 Bias	dBm	_	+20	

^{4.} Values shown include through loss calibrated out of RF test circuit.

Typical 75 Ω Performance⁵ @ +25°C using Wideband RF Circuit Design

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss	+2 mA Series Diode Bias / 1.0 V Shunt 1 and 2 Bias +4.5 mA Series Diode Bias / 1.0 V Shunt 1 and 2 Bias 1000 MHz	dB dB	_ _	-1.1 -0.6	_
Attenuation	0 mA / Series Diode and 1.0 V Shunt 1 and 2 Bias 1000 MHz	dB	_	-27	_
Return Loss	+4.5 mA / Series Diode and 1.0 V Shunt 1 and 2 Bias 1000 MHz	dB	_	-10	_

^{5.} Values shown include through loss calibrated out of RF test circuit.

North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macom.com for additional data sheets and product information.

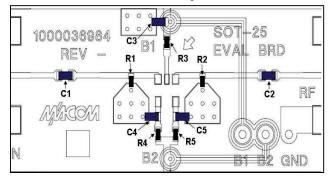
MA4P7455-1225



Quad PIN Diode π Attenuator 10 - 4000 MHz

M/A-COM Products Rev. V2

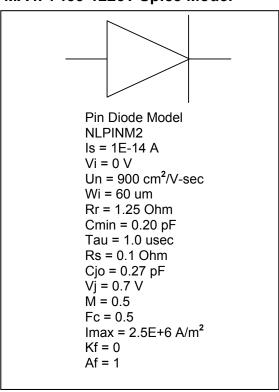
Recommended PCB Layout



Parts List

Part	Value	Case Style	Manufacturer
C1, C2, C3, C4, C5	100 pF	0603	Murata
R1, R2, R3, R4, R5	1000 Ω	0402	Panasonic

MA4P7455-1225T Spice Model



Series and Shunt Diode Bias Currents as a Function of Vseries and Vshunt Voltage (Values shown are PER DIODE)

Vshunt Bias (V)	Vseries Bias (V)	Iseries Diode (mA)	Ishunt Diode (mA)
0.75	0	0.000	0.192
0.75	1	0.106	0.120
0.75	2	0.443	0.048
0.75	3	0/773	0
0.75	4	1.099	0
0.75	5	1.426	0
0.75	6	1.750	0
0.75	7	2.092	0
0.75	8	2.424	0
0.75	9	2.756	0
0.75	10	3.088	0
0.75	11	3.421	0
0.75	12	3.754	0
0.75	13	4.087	0
0.75	14	4.410	0
0.75	15	4.743	0
0.75	16	5.081	0
0.75	17	5.406	0
0.75	18	5.750	0
0.75	19	6.079	0
0.75	20	6.413	0

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype

measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

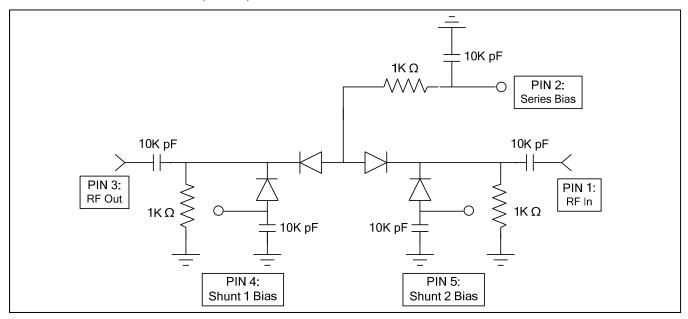
Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macom.com for additional data sheets and product information.



Quad PIN Diode π Attenuator 10 - 4000 MHz

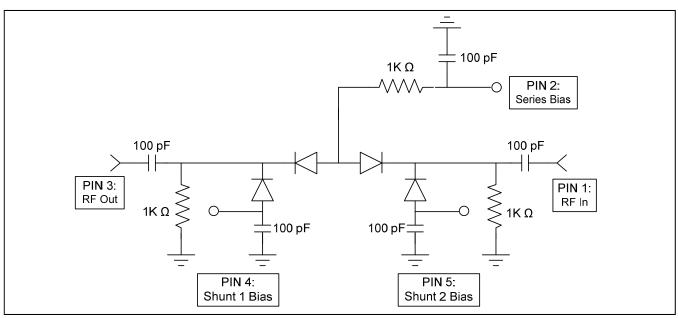
M/A-COM Products Rev. V2

Schematic 10 - 1000 MHz, 50 Ω , RF Circuit 9



9. Keeping PIN 4 & PIN 5 as Separate Bias Points (Same V) reduces RF leakage (increases attenuation) through an otherwise connected Common Anode Bias Note.

Schematic 1 - 4 GHz, 50 Ω, RF Circuit ¹⁰



10. Keeping PIN 4 & PIN 5 as Separate Bias Points (Same V) reduces RF leakage through an otherwise connected Common Anode Bias Node.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not quaranteed.

measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

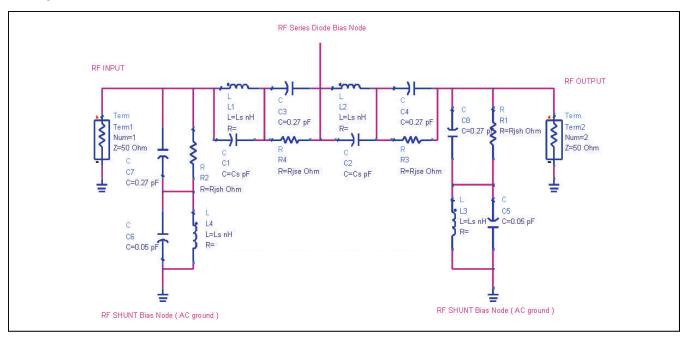
Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.



Quad PIN Diode π Attenuator 10 - 4000 MHz

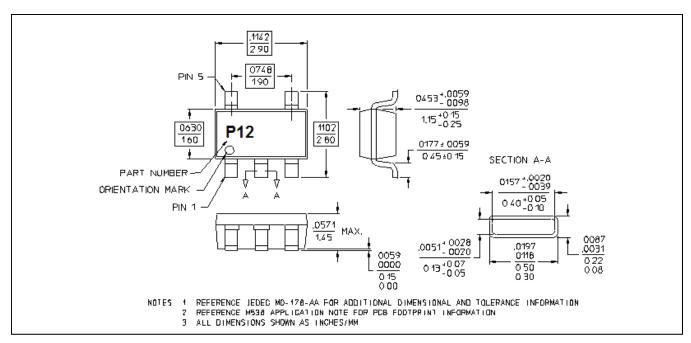
M/A-COM Products Rev. V2

Lumped Element Model for MA4P7455-1225 PIN Diode π Attenuator in SOT-25



Lead Free SOT-25 †

5



[†] Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements.

ADVANCED: Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not quaranteed.

measurements. Commitment to develop is not guaranteed. **PRELIMINARY:** Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
 Visit www.macom.com for additional data sheets and product information.

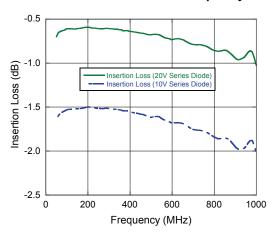


Quad PIN Diode π Attenuator 10 - 4000 MHz

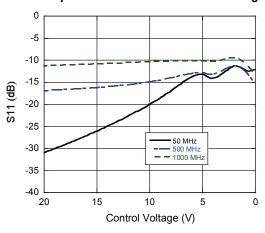
M/A-COM Products Rev. V2

Typical Performance Curves @ +25°C, 50 - 1000 MHz, Shunt Bias = 0.75 Volts

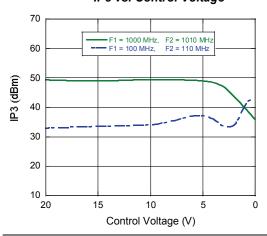
Insertion Loss vs. Frequency



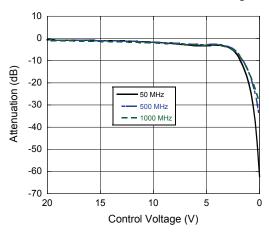
Input Return Loss vs. Control Voltage



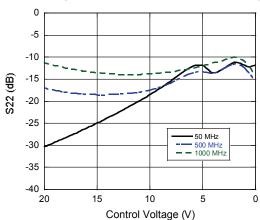
IP3 vs. Control Voltage



Attenuation vs. Control Voltage



Output Return Loss vs. Control Voltage



- **ADVANCED:** Data Sheets contain information regarding a product M/A-COM is considering for development. Performance is based on target specifications, simulated results, and/or prototype
- measurements. Commitment to develop is not guaranteed.

 PRELIMINARY: Data Sheets contain information regarding a product M/A-COM has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298
- Visit www.macom.com for additional data sheets and product information.